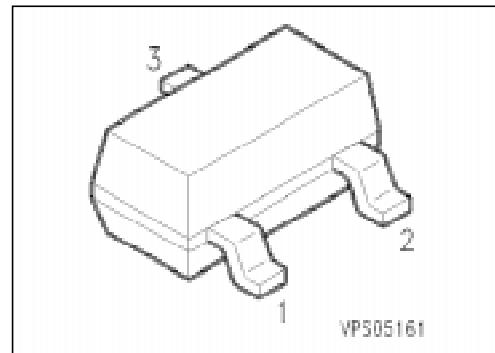


## Silicon Switching Diodes

**BAS 19**  
... **BAS 21**

- High-speed, high-voltage switch



Type	Marking	Ordering Code (tape and reel)	Pin Configuration	Package <sup>1)</sup>
BAS 19	JPs	Q62702-A95	1	SOT-23
BAS 20	JRs	Q62702-A113		
BAS 21	JSS	Q62702-A79	3	

### Maximum Ratings

Parameter	Symbol	Values			Unit
		BAS 19	BAS 20	BAS 21	
Reverse voltage	$V_R$	100	150	200	V
Peak reverse voltage	$V_{RM}$	120	200	250	
Forward current	$I_F$	250			mA
Peak forward current	$I_{FM}$	625			
Total power dissipation, $T_S = 70 \text{ }^\circ\text{C}$	$P_{tot}$	350			mW
Junction temperature	$T_j$	150			$^\circ\text{C}$
Storage temperature range	$T_{stg}$	– 65 ... + 150			

### Thermal Resistance

Junction - ambient <sup>2)</sup>	$R_{th JA}$	$\leq 300$	K/W
Junction - soldering point	$R_{th JS}$	$\leq 230$	

<sup>1)</sup> For detailed information see chapter Package Outlines.

<sup>2)</sup> Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm<sup>2</sup> Cu.

**Electrical Characteristics**at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

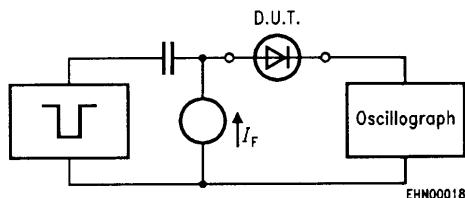
Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**DC characteristics**

Breakdown voltage <sup>1)</sup> $I_{(\text{BR})} = 100 \mu\text{A}$	$V_{(\text{BR})}$	120 200 250	— — —	— — —	V
Forward voltage $I_F = 100 \text{ mA}$ $I_F = 200 \text{ mA}$	$V_F$	— —	— —	1 1.25	
Reverse current $V_R = V_{R \text{ max}}$ $V_R = V_{R \text{ max}}, T_j = 150^\circ\text{C}$	$I_R$	— —	— —	100 100	nA $\mu\text{A}$

**AC characteristics**

Diode capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_D$	—	—	5	pF
Reverse recovery time $I_F = 30 \text{ mA}, I_R = 30 \text{ mA}, R_L = 100 \Omega$ measured at $I_R = 3 \text{ mA}$	$t_{rr}$	—	—	50	ns

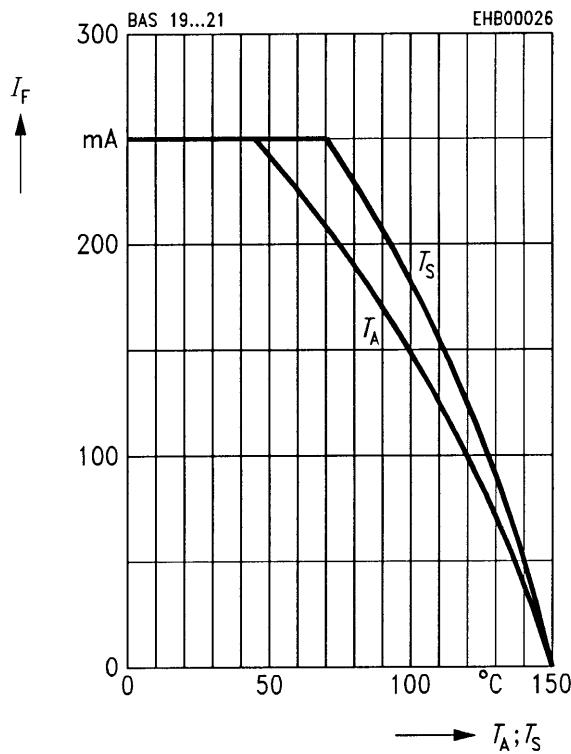
**Test circuit for reverse recovery time**

Pulse generator:  $t_p = 100 \text{ ns}$ ,  $D = 0.05$   
 $t_r = 0.6 \text{ ns}$ ,  $R_j = 50 \Omega$

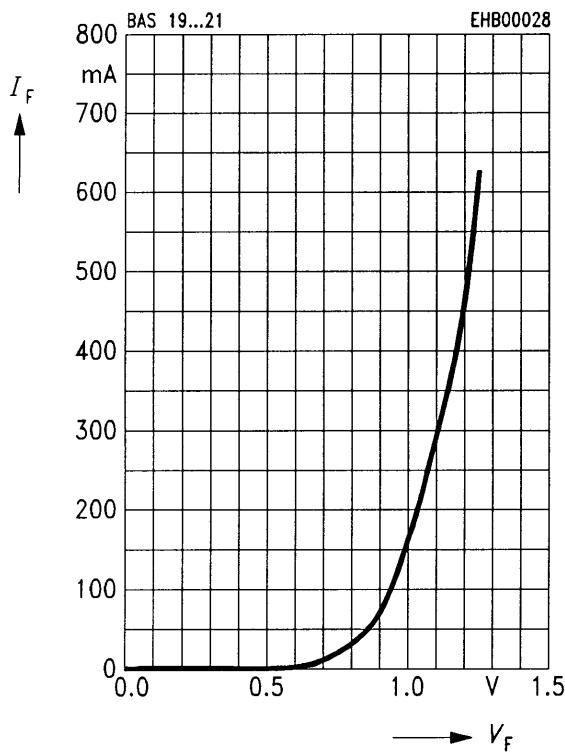
Oscilloscope:  $R = 50 \Omega$   
 $t_r = 0.35 \text{ ns}$   
 $C \leq 1 \text{ pF}$

<sup>1)</sup> Pulse test:  $t_p \leq 300 \mu\text{s}$ ,  $D = 2 \%$ .

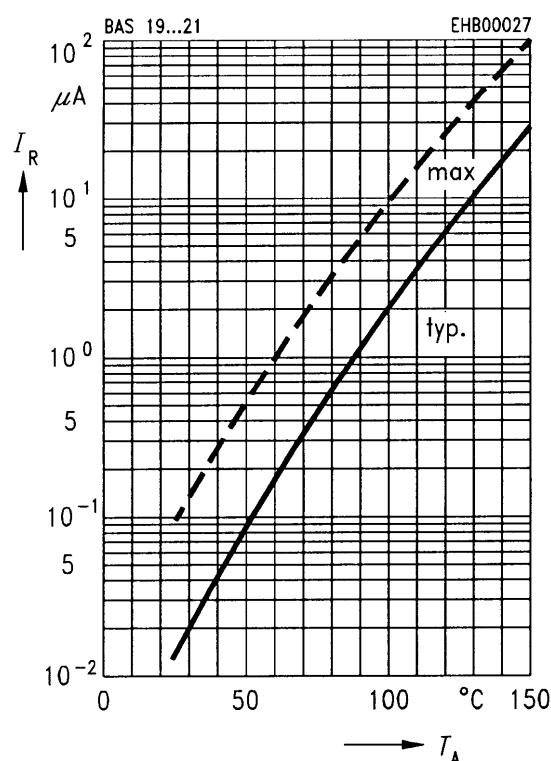
**Forward current**  $I_F = f(T_A^*; T_S)$   
 \* Package mounted on epoxy



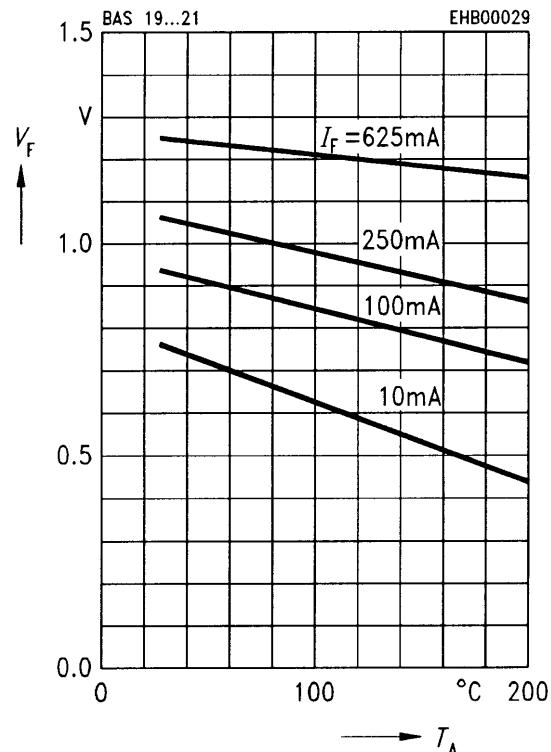
**Forward current**  $I_F = f(V_F)$

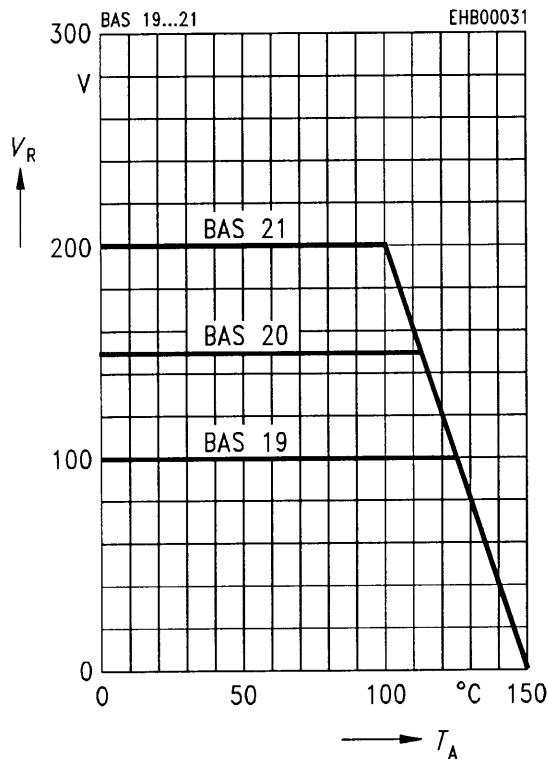


**Reverse current**  $I_R = f(T_A)$



**Forward voltage**  $V_F = f(T_A)$



**Reverse voltage  $V_R = f(T_A)$** **Peak forward current  $I_{FM} = f(t)$** 